

Description

The LX33F40P20 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

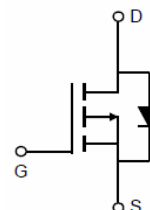
General Features

- $V_{DS} = -20V, I_D = -40A$
 $R_{DS(ON)}$ Typ = $6.6m\Omega$ @ $V_{GS} = -4.5V$
 $R_{DS(ON)}$ Typ = $8.5m\Omega$ @ $V_{GS} = -2.5V$
- High density cell design for ultra low R_{dson}
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation

Application

- Load switch
- Battery protection

Schematic diagram

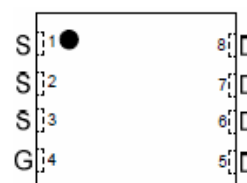


Package



DFN 3.3x3.3 EP top view

Pin Assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
7421	LX33F40P20	DFN 3.3x3.3 EP	-	-	-

Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 12	V
Drain Current-Continuous	I_D	-40	A
Drain Current-Continuous($T_C=100^\circ C$)	$I_D(100^\circ C)$	-30	A
Pulsed Drain Current	I_{DM}	-170	A
Maximum Power Dissipation	P_D	70	W
Derating factor		0.58	W/°C
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{\theta JC}$	1.6	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage V _{GS} =0V, I _D =-250μA			-20	-	-	V
Zero Gate Voltage Drain Current V _{DS} =-16V, V _{GS} =0V			-	-	1	μA
Gate-Body Leakage Current V _{GS} =±12V, V _{DS} =0V			-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.4	-0.6	-1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-15A	-	6.6	8.5	mΩ
		V _{GS} =-2.5V, I _D =-10A	-	8.5	12	
Forward Transconductance	g _{FS}	V _{DS} =-5V, I _D =-20A	80	-	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, F=1.0MHz	-	3500	-	PF
Output Capacitance	C _{oss}		-	577	-	PF
Reverse Transfer Capacitance	C _{rss}		-	445	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =-10V, R _{GEN} =3Ω V _{GS} =-4.5V, R _L =0.5Ω	-	18	-	nS
Turn-on Rise Time	t _r		-	42	-	nS
Turn-Off Delay Time	t _{d(off)}		-	85	-	nS
Turn-Off Fall Time	t _f		-	23	-	nS
Total Gate Charge	Q _g	V _{DS} =-10V, I _D =-20A, V _{GS} =-4.5V	-	55	-	nC
Gate-Source Charge	Q _{gs}		-	10	-	nC
Gate-Drain Charge	Q _{gd}		-	15	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V, I _S =-20A	-	-	-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-45	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = -10A di/dt = 100A/μs (Note 3)	-	47	-	nS
Reverse Recovery Charge	Q _{rr}		-	53	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production

Typical Electrical and Thermal Characteristics (Curves)

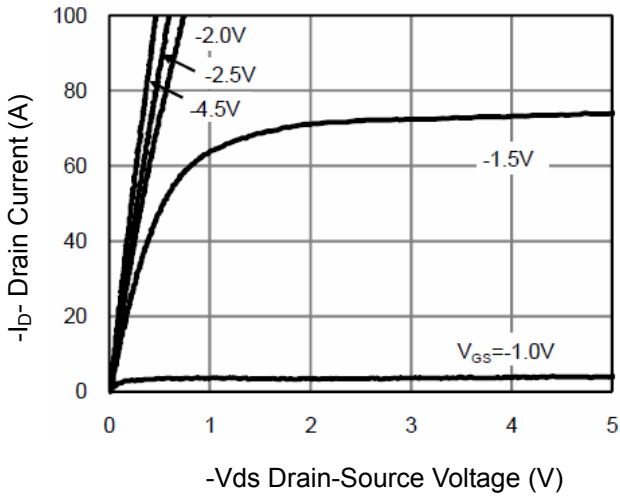


Figure 1 Output Characteristics

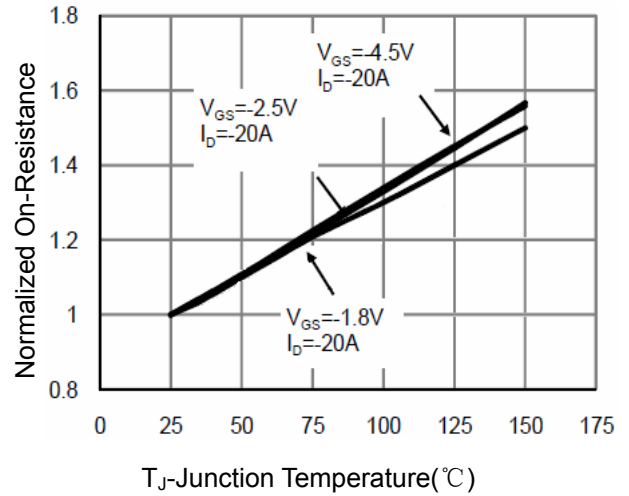


Figure 4 Rdson-Junction Temperature

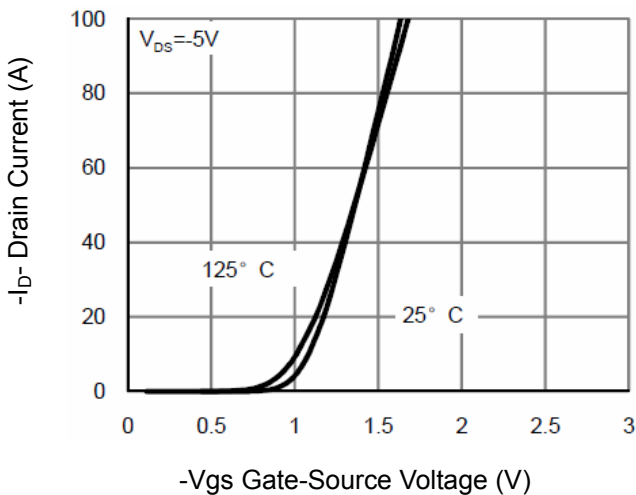


Figure 2 Transfer Characteristics

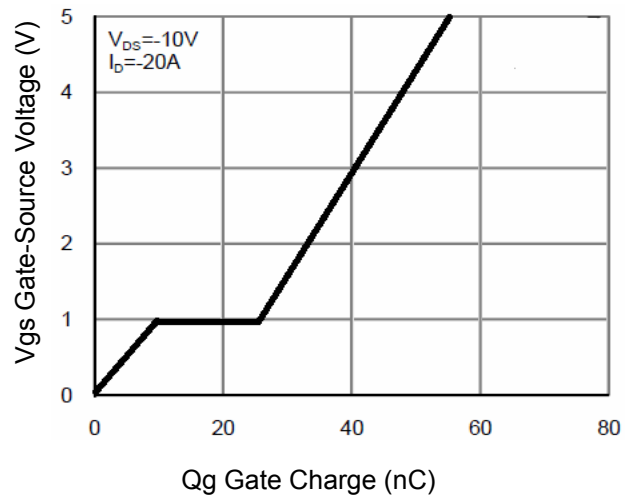


Figure 5 Gate Charge

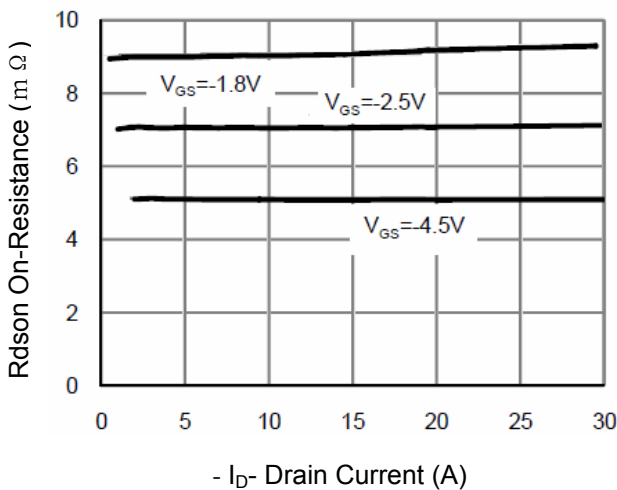


Figure 3 Rdson- Drain Current

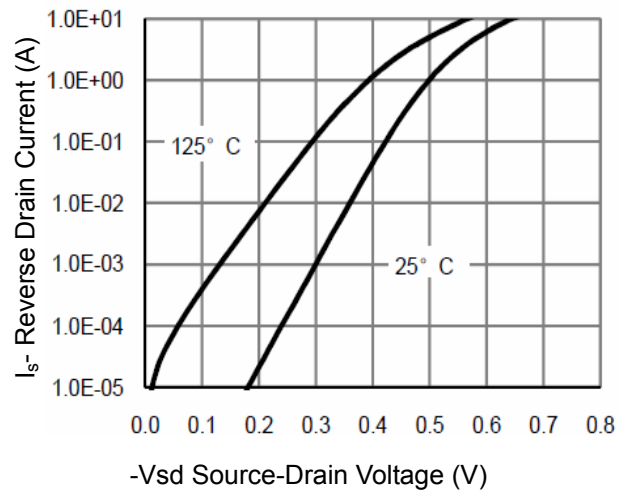


Figure 6 Source- Drain Diode Forward

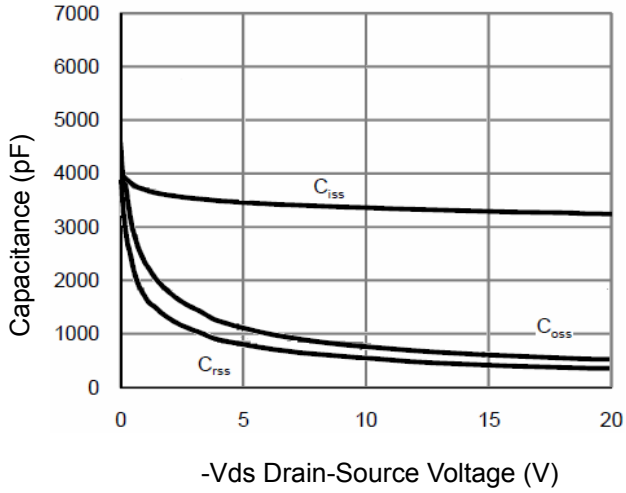


Figure 7 Capacitance vs Vds

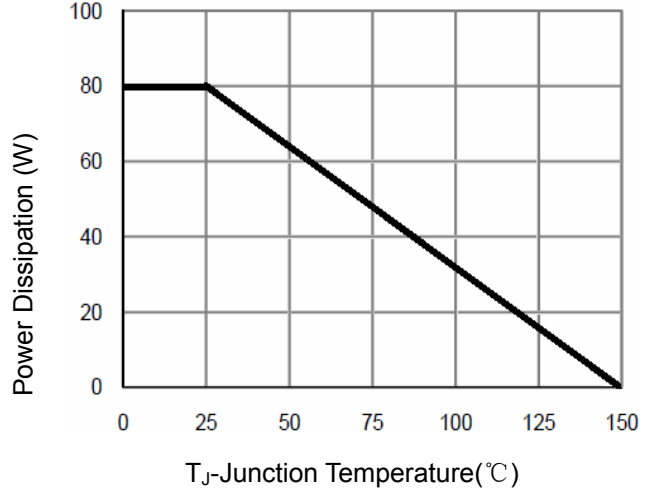


Figure 9 Power De-rating

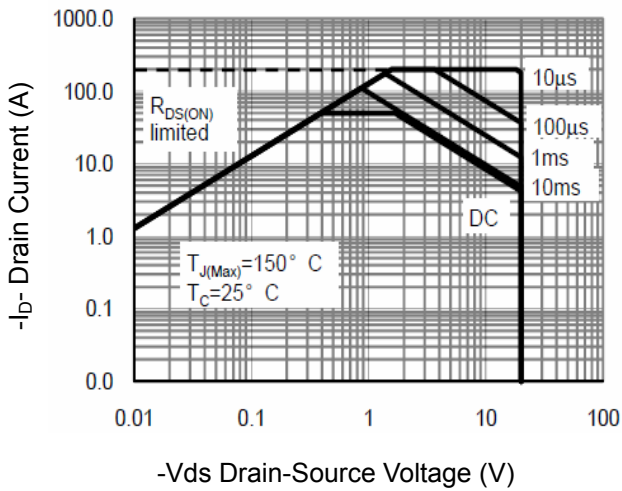


Figure 8 Safe Operation Area

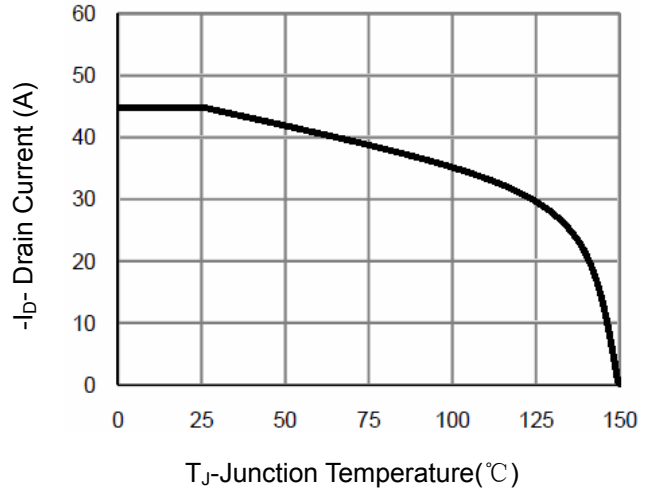


Figure 10 -Current De-rating

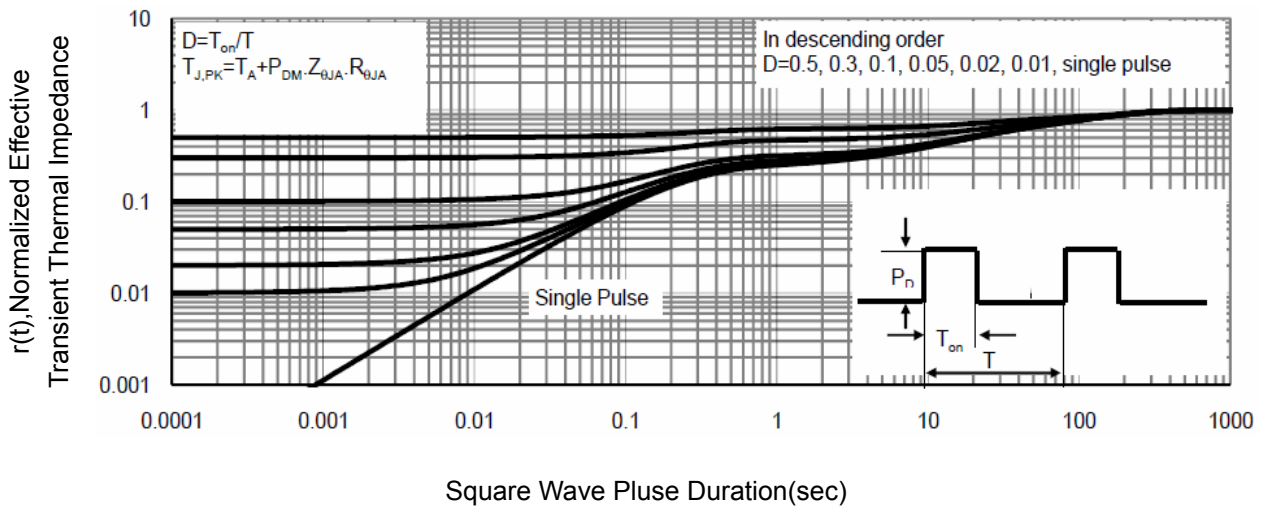


Figure 11 Normalized Maximum Transient Thermal Impedance

DFN3.3X3.3 EP Package Information

封装外形尺寸图			
<p>The diagram shows three views of the DFN3.3X3.3 EP package: a top view with dimensions A, B, C, and D; a side view with dimensions D and L; and a bottom view with dimensions F, H, J, K, L, M, and N. The package is a square with a central square pad and four corner pads.</p>	单位: mm		
	符号	MIN	MAX
A	0.75	0.85	0.8
B	0.25	0.35	0.3
C	0.18	0.22	0.2
D	3.2	3.3	3.25
E	3.2	3.3	3.25
F	2.2	2.5	2.35
G	1.8	2.0	1.9
H	0.3	0.4	0.35
I	0.15	0.25	0.2
J	0.4	0.5	0.45
K	0.6	0.7	0.65
L	1.38	1.58	1.48
M	1.8	2.1	1.95
N	0.15*45°		
O	0.4	0.5	0.45